MMBFJ309L, MMBFJ310L, SMMBFJ309L, SMMBFJ310L

JFET - VHF/UHF Amplifier Transistor

N–Channel

Features

- Drain and Source are Interchangeable
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	25	Vdc
Gate-Source Voltage	V _{GS}	25	Vdc
Gate Current	I _G	10	mAdc

THERMAL CHARACTERISTICS

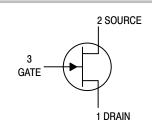
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR–5 Board, (Note 1) T _A = 25°C Derate above 25°C	P _D	225 1.8	mW mW/°C
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	556	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.



ON Semiconductor®

www.onsemi.com





SOT-23 (TO-236) CASE 318 STYLE 10

MARKING DIAGRAM



6x = Device Code

- x = U for MMBFJ309L, SMMBFJ309L
- x = T for MMBFJ310L, SMMBFJ310L
- M = Date Code*

= Pb–Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Package	Shipping [†]
MMBFJ309LT1G,	SOT-23	3,000 / Tape &
SMMBFJ309LT1G	(Pb-Free)	Reel
MMBFJ310LT1G,	SOT-23	3,000 / Tape &
SMMBFJ310LT1G	(Pb-Free)	Reel
SMMBFJ310LT3G	SOT-23 (Pb-Free)	10,000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

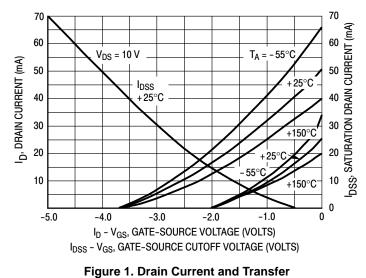
MMBFJ309L, MMBFJ310L, SMMBFJ309L, SMMBFJ310L

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

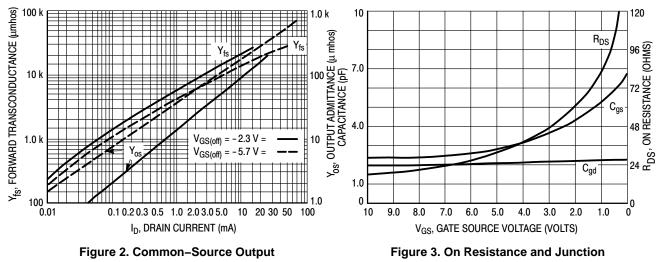
Characteristic		Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS						
Gate–Source Breakdown Voltage $(I_G = -1.0 \ \mu Adc, \ V_{DS} = 0)$		V _{(BR)GSS}	-25	-	-	Vdc
Gate Reverse Current (V _{GS} = -15 Vdc) (V _{GS} = -15 Vdc, T _A = 12	5°C)	I _{GSS}			-1.0 -1.0	nAdc μAdc
Gate Source Cutoff Voltage $(V_{DS} = 10 \text{ Vdc}, I_D = 1.0 \text{ nAdc})$	MMBFJ309 MMBFJ310, SMMBFJ310	V _{GS(off)}	-1.0 -2.0	-	-4.0 -6.5	Vdc
ON CHARACTERISTICS						-
Zero–Gate–Voltage Drain Current $(V_{DS} = 10 \text{ Vdc}, V_{GS} = 0)$	MMBFJ309 MMBFJ310, SMMBFJ310	I _{DSS}	12 24		30 60	mAdc
Gate-Source Forward Voltage $(I_G = 1.0 \text{ mAdc}, V_{DS} = 0)$		V _{GS(f)}	-	-	1.0	Vdc
SMALL-SIGNAL CHARACTERISTICS			•	•	•	•
Forward Transfer Admittance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$		Y _{fs}	8.0	-	18	mmhos
Output Admittance $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 1.0 \text{ kHz})$		y _{os}	-	-	250	μmhos
Input Capacitance $(V_{GS} = -10 \text{ Vdc}, V_{DS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$		C _{iss}	-	-	5.0	pF
Reverse Transfer Capacitance $(V_{GS} = -10 \text{ Vdc}, V_{DS} = 0 \text{ Vdc}, f = 1.0 \text{ MHz})$		C _{rss}	-	-	2.5	pF
Equivalent Short–Circuit Input Noise Voltage $(V_{DS} = 10 \text{ Vdc}, I_D = 10 \text{ mAdc}, f = 100 \text{ Hz})$		ēn	-	10	-	nV/\sqrt{Hz}

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

MMBFJ309L, MMBFJ310L, SMMBFJ309L, SMMBFJ310L



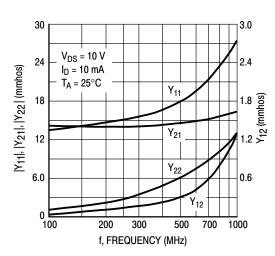
Characteristics versus Gate–Source Voltage



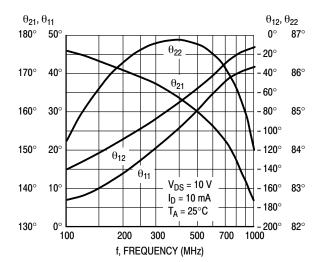
Admittance and Forward Transconductance versus Drain Current

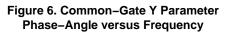
Capacitance versus Gate-Source Voltage

MMBFJ309L, MMBFJ310L, SMMBFJ309L, SMMBFJ310L









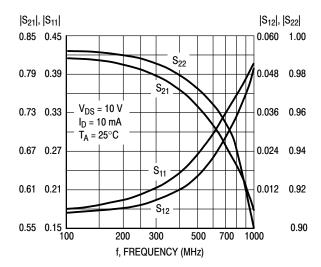


Figure 5. Common–Gate S Parameter Magnitude versus Frequency

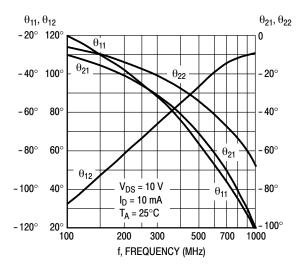


Figure 7. S Parameter Phase–Angle versus Frequency





© Semiconductor Components Industries, LLC, 2019

ON Semiconductor and are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of ON Semiconductor's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using ON Semiconductor products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by ON Semiconductor. "Typical" parameters which may be provided in ON Semiconductor date sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. ON Semiconductor does not convey any license under its patent rights nor the rights of others. ON Semiconductor products are not designed, intended, or authorized for use a a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use ON Semiconductor houteds for any such unintended or unauthorized application, Buyer shall indemnify and hold ON Semiconductor and its officers, employees, subsidiaries

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT:

TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative